SGM4578 8-Bit Bidirectional Voltage-Level Translator for Open-Drain and Push-Pull Applications

GENERAL DESCRIPTION

This 8-bit non-inverting translator is a bidirectional voltage-level translator and can be used to establish digital switching compatibility between mixed-voltage systems. It uses two separate configurable power-supply rails, with the A ports supporting operating voltages from 1.65V to 5.5V while it tracks the V_{CCA} supply, and the B ports supporting operating voltages from 2.3V to 5.5V while it tracks the V_{CCB} supply. This allows the support of both lower and higher logic signal levels while providing bidirectional translation capabilities between any of the 1.8V, 2.5V, 3.3V and 5V voltage nodes.

When the output-enable (OE) input is low, all I/Os are placed in the high-impedance state, which significantly reduces the power-supply quiescent current consumption. OE has an internal pull-down current source, as long as V_{CCA} is powered.

To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pull-down resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

The SGM4578 is available in the Green TSSOP-20 and TQFN- $3\times3-20L$ packages. It operates over an ambient temperature range of -40°C to +85°C.

FEATURES

- No Direction-Control Signal Needed
- Data Rates
 24Mbps (Push-Pull)
 2Mbps (Open-Drain)
- 1.65V to 5.5V on A Ports and 2.3V to 5.5V on B Ports (V_{CCA} ≤ V_{CCB})
- V_{cc} Isolation: If Either V_{cc} is at GND, Both Ports are in the High-Impedance State
- No Power-Supply Sequencing Required: Either V_{CCA} or V_{CCB} can be Ramped First
- I_{OFF}: Supports Partial-Power-Down Mode Operation
- -40°C to +85°C Operating Temperature Range
- Available in Green TSSOP-20 and TQFN-3×3-20L Packages

APPLICATIONS

I²C/SMBus UART GPIO

TYPICAL APPLICATION



Figure 1. Typical Application Circuit

PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
0.014570	TSSOP-20	-40°C to +85°C	SGM4578YTS20G/TR	SGM4578YTS20 XXXXX	Tape and Reel, 4000
SGM4578	TQFN-3×3-20L	-40℃ to +85℃	SGM4578YTQG20G/TR	SGM 4578QG XXXXX	Tape and Reel, 4000

MARKING INFORMATION

NOTE: XXXXX = Date Code and Vendor Code.

X	XX	XX
		Vendor Code
	[—— Date Code - Week
		—— Date Code - Year

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

OVERSTRESS CAUTION

Stresses beyond those listed may cause permanent damage to the device. Functional operation of the device at these or any other conditions beyond those indicated in the operational section of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time.

ESD SENSITIVITY CAUTION

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

SGM4578

ABSOLUTE MAXIMUM RATINGS

Supply Voltage Range	
V _{CCA}	0.3V to 6V
V _{CCB}	0.3V to 6V
A Ports, B Ports, OE Input Voltage Ran	ge, VI ⁽¹⁾
Voltage Range Applied to Any Output i	
or Power-Off State, V $_{0}$ $^{(1)}$	
A Ports	0.3V to 6V
B Ports	0.3V to 6V
Voltage Range Applied to Any Output	it in the High or Low
State, V ₀ ^{(1) (2)}	
A Ports	0.3V to V _{CCA} + 0.3V
B Ports	0.3V to V _{CCB} + 0.3V
Input Clamp Current, I _{IK} (V _I < 0)	50mA
Output Clamp Current, I _{OK} (V _O < 0)	
Continuous Output Current, Io	±50mA
Continuous Current through V _{CCA} , V _{CCB}	, or GND ±100mA
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
НВМ	4000V
MM	
CDM	

NOTES:

1. The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed. 2. The value of V_{CCA} and V_{CCB} are provided in the recommended operating conditions table.

RECOMMENDED OPERATING CONDITIONS

Supply Voltage Range ⁽⁵⁾
V _{CCA} 1.65V to 5.5V
V _{CCB} 2.3V to 5.5V
High-Level Input Voltage, V _{IH}
A Port I/Os (V_{CCA} = 1.65V, V_{CCB} = 2.3V to 5.5V)
V_{CCI} - 0.1V to V_{CCI}
A Port I/Os (V _{CCA} = 1.95V to 5.5V, V _{CCB} = 2.3V to 5.5V)
V_{CCI} - 0.4V to V_{CCI}
B Port I/Os V_{CCI} - 0.4V to V_{CCI}
OE InputV _{CCA} × 0.8V to 5.5V
Low-Level Input Voltage, V _{IL}
A Port I/Os0V to 0.15V
B Port I/Os0V to 0.15V
OE Input0V to V _{CCA} × 0.25V
Operating Temperature Range40°C to +85°C

NOTES:

3. V_{CCI} is the V_{CC} associated with the input ports.

4. V_{CCO} is the V_{CC} associated with the output ports.

5. V_{CCA} must be less than or equal to $V_{\text{CCB}},$ and V_{CCA} must not exceed 5.5V.

PIN CONFIGURATIONS





TQFN-3×3-20L

PIN DESCRIPTION

PIN			TYPE	FUNCTION
TSSOP-20	TQFN-3×3-20L	NAME	TYPE	FUNCTION
1	19	A1	I/O	Input/Output 1. Referenced to V _{CCA} .
2	20	V _{CCA}	S	A Ports Supply Voltage. 1.65V \leq V _{CCA} \leq 5.5V and V _{CCA} \leq V _{CCB} .
3	1	A2	I/O	Input/Output 2. Referenced to V _{CCA} .
4	2	A3	I/O	Input/Output 3. Referenced to V _{CCA} .
5	3	A4	I/O	Input/Output 4. Referenced to V _{CCA} .
6	4	A5	I/O	Input/Output 5. Referenced to V _{CCA} .
7	5	A6	I/O	Input/Output 6. Referenced to V _{CCA} .
8	6	A7	I/O	Input/Output 7. Referenced to V _{CCA} .
9	7	A8	I/O	Input/Output 8. Referenced to V _{CCA} .
10	8	OE	Ι	Output Enable (Active High). Pull OE low to place all outputs in 3-state mode. Referenced to V_{CCA} .
11	9	GND	S	Ground.
12	10	B8	I/O	Input/Output 8. Referenced to V _{CCB} .
13	11	B7	I/O	Input/Output 7. Referenced to V _{CCB} .
14	12	B6	I/O	Input/Output 6. Referenced to V _{CCB} .
15	13	B5	I/O	Input/Output 5. Referenced to V _{CCB} .
16	14	B4	I/O	Input/Output 4. Referenced to V _{CCB} .
17	15	B3	I/O	Input/Output 3. Referenced to V _{CCB} .
18	16	B2	I/O	Input/Output 2. Referenced to V _{CCB} .
19	17	V _{CCB}	S	B Ports Supply Voltage. $2.3V \le V_{CCB} \le 5.5V$.
20	18	B1	I/O	Input/Output 1. Referenced to V _{CCB} .
_	Exposed Pad	GND	_	Exposed pad should be soldered to PCB board and connected to GND or left floating.

ELECTRICAL CHARACTERISTICS

(V_{CCA} = 1.65V to 5.5V, V_{CCB} = 2.3V to 5.5V, Full = -40°C to +85°C, typical values are at T_A = +25°C, unless otherwise noted.)

PARAMETER		CONDITIONS		TEMP	MIN	TYP	MAX	UNITS
ELECTRICAL CHARACTER	RISTICS							
A Ports High Level Output Vo	oltage (V _{OHA})	$I_{OH} = -20\mu A, V_{IB} \ge 1$	V _{CCB} - 0.4V	Full	$V_{CCA} \times 0.67$			
A Ports Low Level Output Vo	ltage (V _{OLA})	$I_{OL} = 1mA, V_{IB} \le 0.$	15V	Full			0.4	v
B Ports High Level Output Ve	oltage (V _{OHB})	I _{OH} = -20μA, V _{IA} ≥ V	V _{CCA} - 0.4V	Full	V _{CCB} × 0.67			
B Ports Low Level Output Vo	oltage (V _{OLB})	$I_{OL}=1mA,V_{IA}\leq0.$	15V	Full			0.4	
Input Leakage Current (I _I)	OE			+25°C			±1	
	UL			Full			±1.5	μA
	A Ports	$V_{CCA} = 0V, V_{CCB} = 0$	0V to 5.5V	+25°C			±0.5	
Power Off Leakage Current	ATOILS		00 10 5.00	Full			±1	μA
(I _{OFF})	B Ports	$V_{aa} = 0V to 5.5V$	$V_{aaa} = 0V$	+25°C			±0.5	μΛ
	D Ports	$V_{CCA} = 0V$ to 5.5V, $V_{CCB} = 0V$		Full			±1	
3-State Output Leakage	A or B Ports	OE = 0V		+25°C			±0.5	μA
(I _{oz})	A OI DI OILS	02-00	Full			±1	μΛ	
		$V_1 = V_0 = OPEN,$ $I_0 = 0$	V_{CCA} = 1.65V to V_{CCB} , V_{CCB} = 2.3V to 5.5V	Full			13	
Quiescent Supply Current (Ic	(ACCA)		V_{CCA} = 5.5V, V_{CCB} = 0V	Full			13	μΑ
			V_{CCA} = 0V, V_{CCB} = 5.5V	Full			-1	
		$V_1 = V_0 = OPEN,$	V_{CCA} = 1.65V to V_{CCB} , V_{CCB} = 2.3V to 5.5V	Full			17	
Quiescent Supply Current (Ic	ссв)	$I_0 = 0$	V_{CCA} = 5.5V, V_{CCB} = 0V	Full			-1	μA
			V_{CCA} = 0V, V_{CCB} = 5.5V	Full			8	
Quiescent Supply Current (I _{CCA} + I _{CCB})		$V_1 = V_0 = OPEN,$ $I_0 = 0$	V_{CCA} = 1.65V to V_{CCB} , V_{CCB} = 2.3V to 5.5V	Full			21	μA
Quiescent Supply Current (I _{CCZA})		$V_1 = V_{CC1} \text{ or } 0V,$ $I_0 = 0, OE = 0V$	V_{CCA} = 1.65V to V_{CCB} , V_{CCB} = 2.3V to 5.5V	Full			13	μA
Quiescent Supply Current (I _{CCZB})		$V_1 = V_{CC1} \text{ or } 0V,$ $I_0 = 0, OE = 0V$	V_{CCA} = 1.65V to V_{CCB} , V_{CCB} = 2.3V to 5.5V	Full			8	μA
OE Input Capacitance (C _I)		V_{CCA} = 3.3V, V_{CCB} =	= 3.3V	+25°C		6		pF
Input/Output Capacitance A	Ports (C _{IO})	V _{CCA} = 3.3V. V _{CCB} =	- 2 2)/	+25°C		6		ьE
Input/Output Capacitance B	Ports (C _{IO})	$v_{CCA} - 3.3v, v_{CCB}$	- 3.3V	+25°C		6		— pF

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TIMING REQUIREMENTS

	DADAMETED		V _{CCB} = 2.5V	V _{CCB} = 3.3V	V _{CCB} = 5V	
	PARAMETER		ТҮР	ТҮР	ТҮР	UNITS
(T _A = +25°C, V _{CCA} = 1.8)	/, unless otherwise noted.)					
Data Rate	Push-Pull Driving		24	24	24	Mbps
Dala Rale	Open-Drain Driving		2	2	2	winhe
Dulas Duration (t)	Push-Pull Driving	Data Innuita	41	41	41	
Pulse Duration (t_w)	Open-Drain Driving	 Data Inputs 	500	500	500	- ns
$(T_A = +25^{\circ}C, V_{CCA} = 2.5)$	/, unless otherwise noted.)		·	-		
Data Data	Push-Pull Driving Open-Drain Driving		24	24	24	Mbps
Data Rate			2	2	2	
Dula Dunation (t.)	Push-Pull Driving	Dete lande	41	41	41	– ns
Pulse Duration (t_W)	Open-Drain Driving	 Data Inputs 	500	500	500	
$(T_A = +25^{\circ}C, V_{CCA} = 3.3)$	/, unless otherwise noted.)		·			
Data Rate	Push-Pull Driving			24	24	Mbps
Dala Rale	Open-Drain Driving			2	2	
Dulas Duration (t.)	Push-Pull Driving	Data Innuta		41	41	
Pulse Duration (t_W)	Open-Drain Driving	 Data Inputs 		500	500	ns
(T _A = +25°C, V _{CCA} = 5V,	unless otherwise noted.)		·			
Data Data	Push-Pull Driving	Push-Pull Driving			24	Maria
Data Rate	Open-Drain Driving				2	Mbps
Dulas Duration (t.)	Push-Pull Driving	Data Innut-			41	
Pulse Duration (t_W)	Open-Drain Driving	 Data Inputs 			500	ns

SWITCHING CHARACTERISTICS

(T_A = +25°C, V_{CCA} = 1.8V, unless otherwise noted.)

PARAMETER	FROM	то	TEST	V _{CCB} = 2.5V	V _{CCB} = 3.3V	V _{CCB} = 5V	UNITS	
PARAIVIETER	(INPUT)	(OUTPUT)	CONDITIONS	TYP	ТҮР	TYP		
t _{PHL}			Push-Pull Driving	3.5	3.5	5.1		
LPHL	•	P	Open-Drain Driving	56.2	27.0	27.9]	
	A	В	Push-Pull Driving	5.1	4.5	4.4	ns	
t _{PLH}			Open-Drain Driving	142.7	119.8	92.1		
			Push-Pull Driving	3.0	2.8	3.4		
t _{PHL}	в	А	Open-Drain Driving	25.6	25.3	25.4		
+	_	A	Push-Pull Driving	3.7	3.2	2.6	ns	
t _{PLH}			Open-Drain Driving	rain Driving 55.1 49.4	49.4	48.0	1	
t _{EN} (t _{PZH} & t _{PZL})	OE	A or B		28.4	24.6	22.5		
t _{DIS} (t _{PHZ} & t _{PLZ})	OE	A or B		674	677	671	ns	
	A Danta	Rise Time	Push-Pull Driving	7.2	8.1	9.1		
t _{rA}	A Ports	Rise Time	Open-Drain Driving	12.3	11.3	10.1	ns	
	P. Dorto	Rise Time	Push-Pull Driving	7.2	6.1	5.4		
t _{rB}	D POILS	Rise fille	Open-Drain Driving	99.3	72.9	36.7	ns	
+	A Dorto	Fall Time	Push-Pull Driving	5.7	5.9	6.9		
t _{fA}	APOILS	rail line	Open-Drain Driving	3.8	3.6	3.6	ns	
+	D Davida	Fall Time	Push-Pull Driving	7.9	7.8	8.4		
t _{fB}	BPORS	rail lime	Open-Drain Driving	3.5	8.4	5.0	ns	
Data Rate			Push-Pull Driving	24	24	24	Mhna	
Dala Rale			Open-Drain Driving	2	2	2	Mbps	

SWITCHING CHARACTERISTICS (continued)

(T_A = +25°C, V_{CCA} = 2.5V, unless otherwise noted.)

PARAMETER	FROM	то	TEST	V _{CCB} = 2.5V	V _{CCB} = 3.3V	V _{CCB} = 5V	UNITS	
PARAMETER	(INPUT)	(OUTPUT)	CONDITIONS	ТҮР	TYP	TYP		
+			Push-Pull Driving	4.5	4.5	5.0		
t _{PHL}	A	В	Open-Drain Driving	26.2	27.1	26.2		
4	A	Б	Push-Pull Driving	3.8	3.3	3.1	ns	
t _{PLH}			Open-Drain Driving	111.0	95.6	76.0		
+			Push-Pull Driving	4.2	4.0	4.1		
t _{PHL}	в		Open-Drain Driving	25.8	25.5	25.6		
	Б	A	Push-Pull Driving	3.7	3.5	3.6	ns	
t _{PLH}				Open-Drain Driving	52.7	50.6	49.8	
t _{EN} (t _{PZH} & t _{PZL})	OE	A or B		21.6	17.4	15.5		
t _{DIS} (t _{PHZ} & t _{PLZ})	OE	A or B		689	688	678	ns	
	A Dorto [Rise Time	Push-Pull Driving	6.4	6.7	6.9	ns	
t _{rA}	A Ports r	kise nine	Open-Drain Driving	10.5	7.7	7.8		
	D Darta (Rise Time	Push-Pull Driving	6.2	5.4	4.9		
t _{rB}	B Ports F	kise Time	Open-Drain Driving	67.0	50.9	30.5	ns	
	A Dorto	Fall Time	Push-Pull Driving	8.6	8.2	7.3		
t _{fA}	A Ports I	raii nine	Open-Drain Driving	3.6	3.3	3.1	ns	
+	P. Dorto	Fall Time	Push-Pull Driving	8.5	7.7	8.1		
t _{fB}	B Ports I		Open-Drain Driving	3.4	3.9	5.4	ns	
Data Data			Push-Pull Driving	24	24	24	Mhna	
Data Rate			Open-Drain Driving	2	2	2	Mbps	

SWITCHING CHARACTERISTICS (continued)

(T_A = +25°C, V_{CCA} = 3.3V, unless otherwise noted.)

PARAMETER	FROM	то	TEST	V _{CCB} = 3.3V	V _{CCB} = 5V	UNITS
PARAMETER	(INPUT)	(OUTPUT)	CONDITIONS	ТҮР	ТҮР	
4			Push-Pull Driving	4.4	5.0	
t _{PHL}	•	P	Open-Drain Driving	25.5	27.5	
	A	В	Push-Pull Driving	3.5	2.7	ns
t _{PLH}			Open-Drain Driving	52.4	51.4	
			Push-Pull Driving	4.1	4.4	
t _{PHL}	в		Open-Drain Driving	25.8	54.3	
	В	A	Push-Pull Driving	3.1	2.8	ns
t _{PLH}			Open-Drain Driving	50.3	49.4	
t _{EN} (t _{PZH} & t _{PZL})	OE	A or B		15.9	13.8	
t _{DIS} (t _{PHZ} & t _{PLZ})	OE	A or B		699	678	ns
	A Dorto	Rise Time	Push-Pull Driving	5.2	6.2	- ns
t _{rA}	A Ports	Rise filme	Open-Drain Driving	6.3	6.2	
t _{rB}	P. Dorto	Rise Time	Push-Pull Driving	5.3	4.7	20
ι _{rB}	6 Ports	Rise filme	Open-Drain Driving	8.3	6.8	ns
	A Dorto	Fall Time	Push-Pull Driving	7.3	7.6	
t _{fA}	APOILS	Fail Time	Open-Drain Driving	3.1	3.0	ns
	D Darta	Fall Time	Push-Pull Driving	7.7	7.3	
t _{fB}	B Ports	raii Time	Open-Drain Driving	3.8	4.6	ns
Data Data			Push-Pull Driving	24	24	Mhna
Data Rate			Open-Drain Driving	2	2	Mbps

SWITCHING CHARACTERISTICS (continued)

(T_A = +25°C, V_{CCA} = 5V, unless otherwise noted.)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	V _{CCB} = 5V TYP	UNITS
	((001101)			
t _{PHL}			Push-Pull Driving	5.3	_
	А	В	Open-Drain Driving	27.4	ns
t _{PLH}		_	Push-Pull Driving	2.4	
4PLH			Open-Drain Driving	50.6	
+			Push-Pull Driving	5.0	
t _{PHL}	В	٨	Open-Drain Driving	26.3	
	D	A	Push-Pull Driving	2.2	ns
t _{PLH}			Open-Drain Driving	49.3	
t _{EN} (t _{PZH} & t _{PZL})	OE	A or B		22.6	
t _{DIS} (t _{PHZ} & t _{PLZ})	OE	A or B		665	ns
4	A Ports Rise Time		Push-Pull Driving	5.3	20
t _{rA}			Open-Drain Driving	5.0	ns
	D Darta I	Rise Time	Push-Pull Driving	4.9	
t _{rB}	B Ports F	kise nime	Open-Drain Driving	6.5	ns
		Toll Theor	Push-Pull Driving	8.5	
t _{fA}	A Ports I	Fall Time	Open-Drain Driving	2.8	ns
			Push-Pull Driving	7.7	
t _{fB}	B Ports	Fall Time	Open-Drain Driving	4.2	ns
Data Data			Push-Pull Driving	24	Ndb as a
Data Rate			Open-Drain Driving	2	Mbps

PARAMETER MEASUREMENT INFORMATION





NOTES:

- 1. C_L includes probe and jig capacitance.
- 2. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- 3. All input pulses are supplied by generators having the following characteristics: PRR \leq 10MHz, Z₀ = 50 Ω , dv/dt \geq 1V/ns.
- 4. The outputs are measured one at a time, with one transition per measurement.
- 5. t_{PLZ} and t_{PHZ} are the same as t_{DIS} .
- 6. t_{PZL} and t_{PZH} are the same as t_{EN}
- 7. t_{PLH} and t_{PHL} are the same as $t_{\mathsf{PD}}.$
- 8. V_{CCI} is the V_{CC} associated with the input ports.
- 9. V_{CCO} is the V_{CC} associated with the output ports.
- 10. All parameters and waveforms are not applicable to all devices.

DETAILED DESCRIPTION

Overview

The SGM4578 can be used to bridge the digitalswitching compatibility gap between two voltage nodes to successfully interface logic threshold levels found in electronic systems. It should be used in a point-to-point topology for interfacing devices or systems operating at different interface voltages with one another. Its primary target application is for interfacing with open-drain drivers on the data I/Os such as I^2C or 1-wire, where the data is bidirectional and no control signal is available. The SGM4578 can also be used in applications where a push-pull driver is connected to the data I/Os.

Architecture

The SGM4578 architecture (see Figure 3) is an auto-direction-sensing based translator that does not require a direction-control signal to control the direction of data flow from A to B or from B to A.

These two bidirectional channels independently determine the direction of data flow without a direction-control signal. Each I/O pin can be automatically reconfigured as either an input or an output, which is how this auto-direction feature is realized.



Figure 3. Architecture of a SGM4578 Cell

The SGM4578 employs two key circuits to enable this voltage translation:

- An N-channel pass-gate transistor topology that ties the A port to the B port.
- Output one-shot (O.S.) edge-rate accelerator circuitry to detect and accelerate rising edges on the A or B ports.

Input Driver Requirements

The fall time (t_{fA} , t_{fB}) of a signal depends on the output impedance of the external device driving the data I/Os of the SGM4578. Similarly, the t_{PHL} and data rates also depend on the output impedance of the external driver. The values for t_{fA} , t_{fB} , t_{PHL} , and data rates in the datasheet assume that the output impedance of the external driver is less than 50 Ω .

Power Up

During operation, ensure that $V_{CCA} \leq V_{CCB}$ at all times. The sequencing of each power supply will not damage the device during the power up operation, so either power supply can be ramped up first.

Output Load Considerations

We recommend careful PCB layout practices with short PCB trace lengths to avoid excessive capacitive loading and to ensure that proper O.S. triggering takes place. PCB signal trace-lengths should be kept short enough such that the round trip delay of any reflection is less than the one-shot duration. This improves signal integrity by ensuring that any reflection sees a low impedance at the driver. The O.S. circuits have been designed to stay on for approximately 30ns. The maximum capacitance of the lumped load that can be driven also depends directly on the one-shot duration. With very heavy capacitive loads, the one-shot can be time-out before the signal is driven fully to the positive rail. The O.S. duration has been set to optimize trade-offs between dynamic I_{CC}, load driving capability, and maximum bit-rate considerations. Both PCB trace length and connectors add to the capacitance that the SGM4578 output sees, so it is recommended that this lumped-load capacitance be considered to avoid O.S. retriggering, bus contention, output signal oscillations, or other adverse system-level effects.

DETAILED DESCRIPTION (continued)

Enable and Disable

The SGM4578 has an OE input that is used to disable the device by setting OE low, which places all I/Os in the Hi-Z state. OE has an internal pull-down current source, as long as V_{CCA} is powered. The disable time (t_{DIS}) indicates the delay between the time when OE goes low and when the outputs are disabled (Hi-Z). The enable time (t_{EN}) indicates the amount of time the user must allow for the one-shot circuitry to become operational after OE is taken high.

Pull-Up or Pull-Down Resistors on I/O Lines

Each A port I/O has an internal $10k\Omega$ pull-up resistor to V_{CCA} , and each B port I/O has an internal $10k\Omega$ pull-up resistor to V_{CCB} . If a smaller value of pull-up resistor is required, an external resistor must be added from the I/O to V_{CCA} or V_{CCB} (in parallel with the internal $10k\Omega$ resistors). Adding lower value pull-up resistors will affect V_{OL} levels, however. The internal pull-ups of the SGM4578 are disabled when the OE pin is low.

PACKAGE OUTLINE DIMENSIONS

TSSOP-20





RECOMMENDED LAND PATTERN (Unit: mm)





Symbol		nsions meters	Dimensions In Inches		
,	MIN	MAX	MIN	MAX	
A		1.100		0.043	
A1	0.050	0.150	0.002	0.006	
A2	0.800	1.000	0.031	0.039	
b	0.190	0.300	0.007	0.012	
С	0.090	0.200	0.004	0.008	
D	6.400	6.600	0.252	0.259	
E	4.300	4.500	0.169	0.177	
E1	6.250	6.550	0.246	0.258	
е	0.650) BSC	0.026	BSC	
L	0.500	0.700	0.02	0.028	
Н	0.25 TYP		0.01	TYP	
θ	1°	7°	1°	7°	

PACKAGE OUTLINE DIMENSIONS

TQFN-3×3-20L





RECOMMENDED LAND PATTERN (Unit: mm)

Symbol	-	nsions meters	Dimensions In Inches		
	MIN	MAX	MIN	MAX	
А	0.700	0.800	0.028	0.031	
A1	0.000	0.050	0.000	0.002	
A2	0.203	B REF	0.008 REF		
D	2.924	3.076	0.115	0.121	
D1	1.400	1.600	0.055	0.063	
E	2.924	3.076	0.115	0.121	
E1	1.400	1.600	0.055	0.063	
k	0.200 MIN		0.008 MIN		
b	0.150	0.250	0.006	0.010	
е	0.400) TYP	0.016 TYP		
L	0.324	0.476	0.013	0.019	

TAPE AND REEL INFORMATION

REEL DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
TSSOP-20	13″	12.4	6.80	6.85	1.70	4.0	8.0	2.0	12.0	Q1
TQFN-3×3-20L	13″	12.4	3.30	3.30	1.10	4.0	8.0	2.0	12.0	Q2

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton	
13″	386	280	370	5	DD0002